



Sheet 1 of 3

FORM PTO-1449 (Rev. 7-80)	U.S. Dept. of Commerce Patent and Trademark Office	Atty Docket No. 24096 .00500	Serial No. 09/697,203			
INFORMATION DISCLOSURE CITATION (Use several sheets if necessary)						
<table border="1"> <tr> <td>Applicant Kozlowski, Lester J..</td> </tr> <tr> <td>Filing Date October 26, 2000</td> <td>Group 2878</td> </tr> </table>				Applicant Kozlowski, Lester J..	Filing Date October 26, 2000	Group 2878
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*Examiner's Initials		Document Number	Date	Name	Class	Subclass	Filing Date
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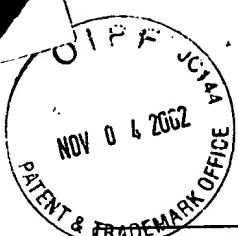
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Examiner		Date Considered 3/19/04

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Applicant
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		Document Number	Date	Country	Class	Subclass	Translation Yes <input checked="" type="checkbox"/> No <input type="checkbox"/>

OTHER PRIOR ART (Including Author, Title, Date, Pertinent Pages, Etc.)

ly	AB	Copy of International Search Report

Examiner *[Signature]* Date Considered *3/19/04*

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